

ULTRALOW-NOISE, HIGH PSRR, FAST RF 1.5 A LOW-DROPOUT LINEAR REGULATORS

FEATURES

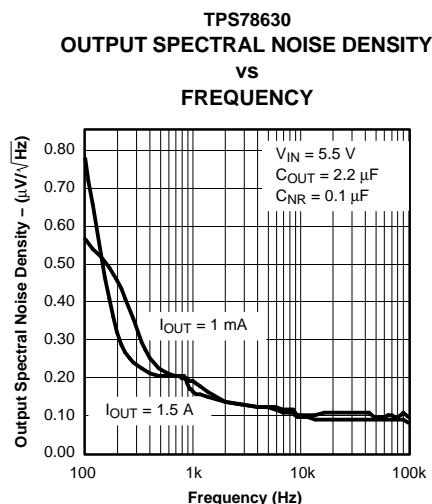
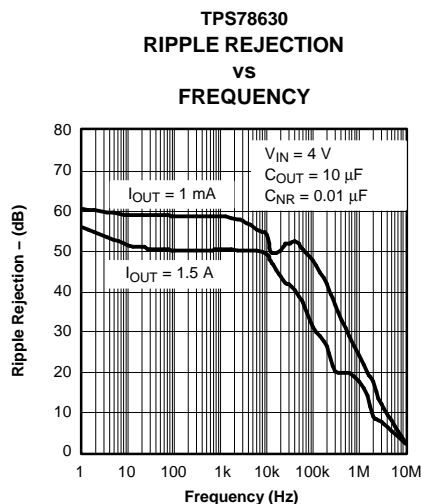
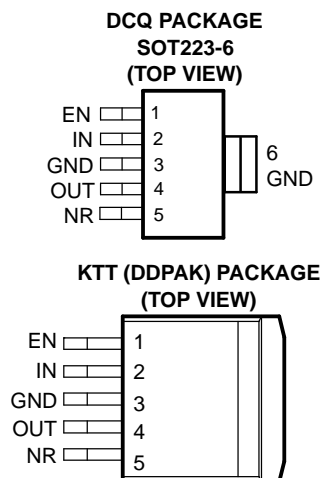
- 1.5 A Low-Dropout Regulator With Enable
- Available in 1.8-V, 2.5-V, 2.8-V, 3-V, 3.3-V, and Adjustable (1.2-V to 5.5-V)
- High PSRR (49 dB at 10 kHz)
- Ultralow Noise (48 μV_{RMS} , TPS79630)
- Fast Start-Up Time (50 μs)
- Stable With a 1- μF Ceramic Capacitor
- Excellent Load/Line Transient Response
- Very Low Dropout Voltage (390 mV at Full Load, TPS78630)
- 6-Pin SOT223-6 and 5-Pin DPAK Package

APPLICATIONS

- RF: VCOs, Receivers, ADCs
- Audio
- Bluetooth™, Wireless LAN
- Cellular and Cordless Telephones
- Handheld Organizers, PDAs

DESCRIPTION

The TPS786xx family of low-dropout (LDO) low-power linear voltage regulators features high power supply rejection ratio (PSRR), ultralow noise, fast start-up, and excellent line and load transient responses in small outline, SOT223-6 and 5-pin DPAK packages. Each device in the family is stable, with a small 1- μF ceramic capacitor on the output. The family uses an advanced, proprietary BiCMOS fabrication process to yield extremely low dropout voltages (e.g., 390 mV at 1.5 A). Each device achieves fast start-up times (approximately 50 μs with a 0.001 μF bypass capacitor) while consuming very low quiescent current (265 μA typical). Moreover, when the device is placed in standby mode, the supply current is reduced to less than 1 μA . The TPS78630 exhibits approximately 48 μV_{RMS} of output voltage at 3.0 V output noise with a 0.1 μF bypass capacitor. Applications with analog components that are noise sensitive, such as portable RF electronics, benefit from the high PSRR, low noise features, and the fast response time.



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

AVAILABLE OPTIONS⁽¹⁾

PRODUCT	VOLTAGE	PACKAGE	T _J	SYMBOL	PART NUMBER	TRANSPORT MEDIA, QUANTITY
TPS78601	1.2 to 5.5 V	SOT223-6	-40°C to 125°C	PS78601	TPS78601DCQ	Tube, 78
		DDPAK			TPS78601DCQR	Tape and Reel, 2500
TPS78618	1.8 V			SOT223-6	PS78618	TPS78601KTT
		DDPAK				TPS78618DCQ
						TPS78618DCQR
TPS78625	2.5 V			SOT223-6	PS78625	
		DDPAK				TPS78625DCQR
						TPS78625KTT
TPS78628	2.8 V			SOT223-6	PS78628	
		DDPAK				TPS78628KTT
TPS78630	3.0 V		SOT223-6	PS78630	TPS78630DCQ	Tube 78
		DDPAK			TPS78630DCQR	Tape and Reel, 2500
					TPS78630KTT	Reel, 500
TPS78633	3.3 V		SOT223-6	PS78633		
		DDPAK			TPS78633KTT	Reel, 500

(1) For the most current package and ordering information, see the Package Option Addendum located at the end of this data sheet.

ABSOLUTE MAXIMUM RATINGS

over operating temperature (unless otherwise noted)⁽¹⁾

	VALUE
V _{IN} range	-0.3 V to 6 V
V _{EN} range	-0.3 V to V _{IN} + 0.3 V
V _{OUT} range	6 V
Peak output current	Internally limited
ESD rating, HBM	2 kV
ESD rating, CDM	500 V
Continuous total power dissipation	See Dissipation Ratings table
Junction temperature range, T _J	-40°C to 150°C
Storage temperature range, T _{stg}	-65°C to 150°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

PACKAGE DISSIPATION RATINGS

PACKAGE	BOARD	R _{θJC}	R _{θJA}
DDPAK	High-K ⁽¹⁾	2 °C/W	23 °C/W
SOT223	Low-K ⁽²⁾	15 °C/W	53 °C/W

- (1) The JEDEC high-K (2s2p) board design used to derive this data was a 3-in x 3-in (7,5-cm x 7,5-cm), multilayer board with 1 ounce internal power and ground planes and 2 ounce copper traces on top and bottom of the board.
- (2) The JEDEC low-K (1s) board design used to derive this data was a 3-in x 3-in (7,5-cm x 7,5cm), two-layered board with 2 ounce copper traces on top of the board.

ELECTRICAL CHARACTERISTICS

Over recommended operating temperature range ($T_J = -40^{\circ}\text{C}$ to 125°C), $V_{EN} = V_{IN}$, $V_{IN} = V_{OUT(nom)} + 1\text{ V}$, $I_{OUT} = 1\text{ mA}$, $C_{OUT} = 10\mu\text{F}$, $C_{NR} = 0.01\mu\text{F}$, unless otherwise noted. Typical values are at 25°C .

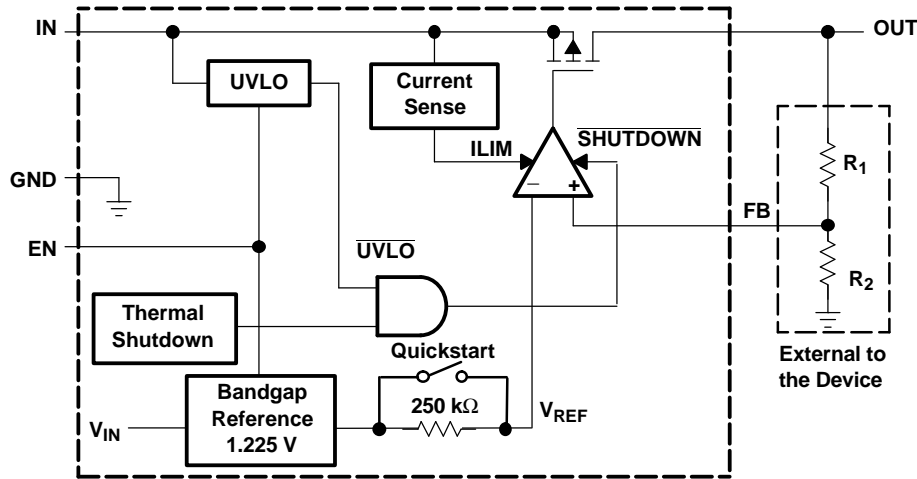
PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
Input voltage, $V_{IN}^{(1)}$				2.7		5.5	V
Continuous output current I_{OUT}				0		1.5	A
Output voltage	TPS78601			V_{FB}		$5.5 - V_{DO}$	V
	TPS78618	$0\mu\text{A} < I_{OUT} < 1.5\text{ A}$	$2.8\text{ V} < V_{IN} < 5.5\text{ V}$	1.764	1.8	1.836	V
	TPS78625	$0\mu\text{A} < I_{OUT} < 1.5\text{ A}$	$3.5\text{ V} < V_{IN} < 5.5\text{ V}$	2.45	2.5	2.55	V
	TPS78628	$0\mu\text{A} < I_{OUT} < 1.5\text{ A}$	$3.8\text{ V} < V_{IN} < 5.5\text{ V}$	2.744	2.8	2.856	V
	TPS78630	$0\mu\text{A} < I_{OUT} < 1.5\text{ A}$	$4\text{ V} < V_{IN} < 5.5\text{ V}$	2.94	3	3.06	V
	TPS78633	$0\mu\text{A} < I_{OUT} < 1.5\text{ A}$	$4.3\text{ V} < V_{IN} < 5.5\text{ V}$	3.234	3.3	3.366	V
Output voltage line regulation ($\Delta V_{OUT}\%/V_{IN}^{(1)}$)		$V_{OUT} + 1\text{ V} < V_{IN} \leq 5.5\text{ V}$			5	12	%/V
Load regulation ($\Delta V_{OUT}\%/V_{OUT}$)		$0\mu\text{A} < I_{OUT} < 1.5\text{ A}$ $T_J = 25^{\circ}\text{C}$			7		mV
Dropout voltage ⁽²⁾ $V_{IN} = V_{OUT(nom)} - 0.1\text{ V}$	TPS78628	$I_{OUT} = 1.5\text{ A}$			410	580	mV
	TPS78630	$I_{OUT} = 1.5\text{ A}$			390	550	
	TPS78633	$I_{OUT} = 1.5\text{ A}$			340	510	
Output current limit		$V_{OUT} = 0\text{ V}$		2.4		4.2	A
Ground pin current		$0\mu\text{A} < I_{OUT} < 1.5\text{ A}$			260	385	μA
Shutdown current ⁽³⁾		$V_{EN} = 0\text{ V}$, $2.7\text{ V} < V_{IN} < 5.5\text{ V}$			0.07	1	μA
FB pin current		FB = 1.8 V				1	μA
Power supply ripple rejection	TPS78630	$f = 100\text{ Hz}$, $I_{OUT} = 10\text{ mA}$			59		dB
		$f = 100\text{ Hz}$, $I_{OUT} = 1.5\text{ A}$			52		
		$f = 10\text{ kHz}$, $I_{OUT} = 1.5\text{ A}$			49		
		$f = 100\text{ kHz}$, $I_{OUT} = 1.5\text{ A}$			32		
Output noise voltage (TPS78630)		BW = 100 Hz to 100 kHz, $I_{OUT} = 1.5\text{ A}$	$C_{NR} = 0.001\mu\text{F}$		66		μV_{RMS}
			$C_{NR} = 0.0047\mu\text{F}$		51		
			$C_{NR} = 0.01\mu\text{F}$		49		
			$C_{NR} = 0.1\mu\text{F}$		48		
Time, start-up (TPS78630)		$R_L = 2\Omega$, $C_{OUT} = 1\mu\text{F}$	$C_{NR} = 0.001\mu\text{F}$		50		μs
			$C_{NR} = 0.0047\mu\text{F}$		75		
			$C_{NR} = 0.01\mu\text{F}$		110		
High-level enable input voltage		$2.7\text{ V} < V_{IN} < 5.5\text{ V}$		1.7		V_{IN}	V
Low-level enable input voltage		$2.7\text{ V} < V_{IN} < 5.5\text{ V}$		0		0.7	V
EN pin current		$V_{EN} = 0$		-1		1	μA
UVLO threshold		V_{CC} rising		2.25		2.65	V
UVLO hysteresis					100		mV

(1) Minimum $V_{IN} = V_{OUT} + V_{DO}$ or 2.7 V, whichever is greater.

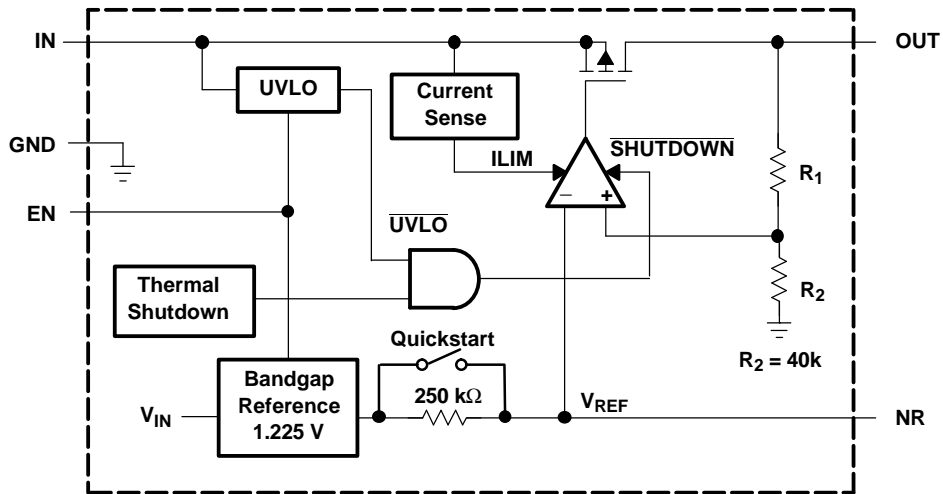
(2) Dropout is not measured for TPS78618 or TPS78625 since minimum $V_{IN} = 2.7\text{ V}$.

(3) For adjustable version, this applies only after V_{IN} is applied; then V_{EN} transitions high to low.

FUNCTIONAL BLOCK DIAGRAM—ADJUSTABLE VERSION



FUNCTIONAL BLOCK DIAGRAM—FIXED VERSION



Terminal Functions

TERMINAL			DESCRIPTION
NAME	ADJ	FIXED	
NR	NA	5	An external bypass capacitor, connected to this terminal, in conjunction with an internal resistor, creates a low-pass filter to further reduce regulator noise.
EN	1	1	The EN terminal is an input which enables or shuts down the device. When EN goes to a logic high, the device will be enabled. When the device goes to a logic low, the device is in shutdown mode.
FB	5	N/A	This terminal is the feedback input voltage for the adjustable device.
GND	3, Tab	3, Tab	Regulator ground
IN	2	2	Unregulated input to the device.
OUT	4	4	Output of the regulator.

TYPICAL CHARACTERISTICS

TPS78630
OUTPUT VOLTAGE
VS
OUTPUT CURRENT

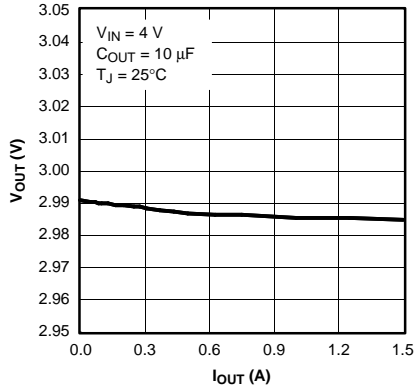


Figure 1.

TPS78628
OUTPUT VOLTAGE
VS
JUNCTION TEMPERATURE

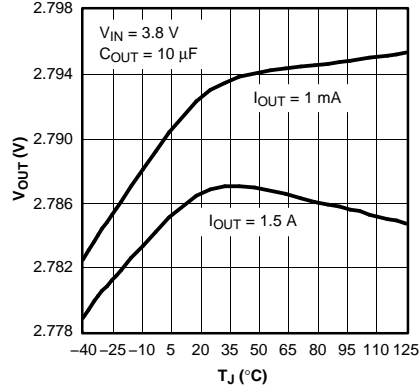


Figure 2.

TPS78628
GROUND CURRENT
VS
JUNCTION TEMPERATURE

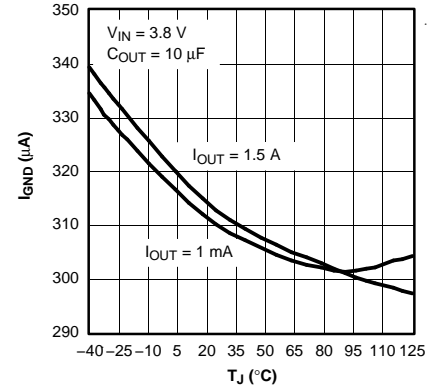


Figure 3.

TPS78630
OUTPUT SPECTRAL NOISE DEN-
SITY
VS
FREQUENCY

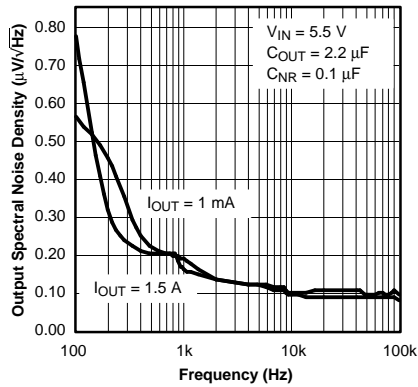


Figure 4.

TPS78630
OUTPUT SPECTRAL NOISE DEN-
SITY
VS
FREQUENCY

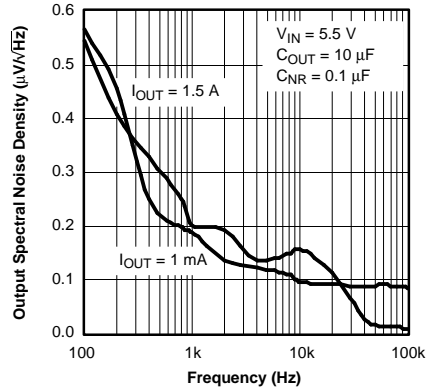


Figure 5.

TPS78630
OUTPUT SPECTRAL NOISE DEN-
SITY
VS
FREQUENCY

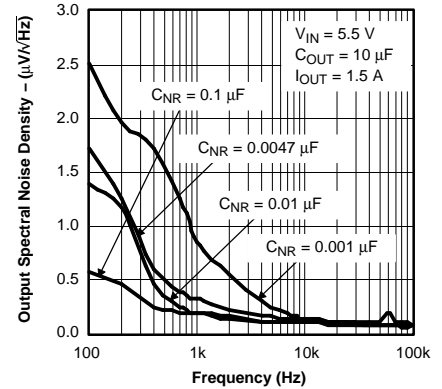


Figure 6.

TYPICAL CHARACTERISTICS (continued)

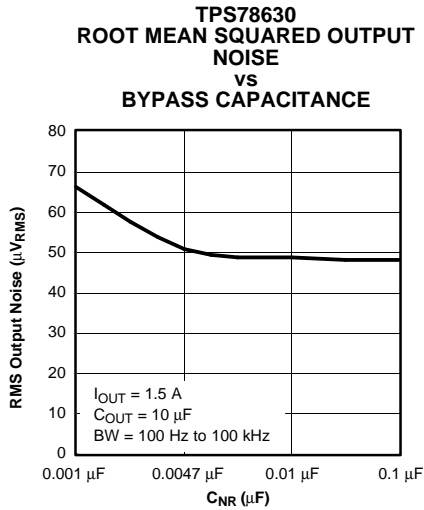


Figure 7.

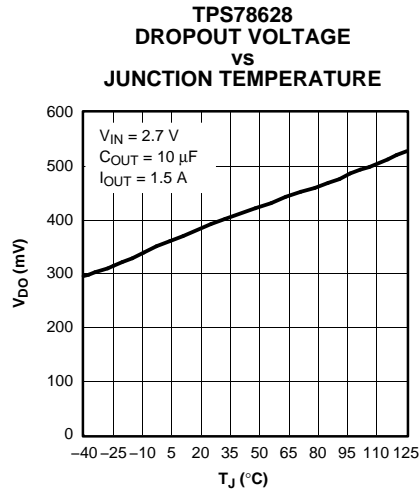


Figure 8.

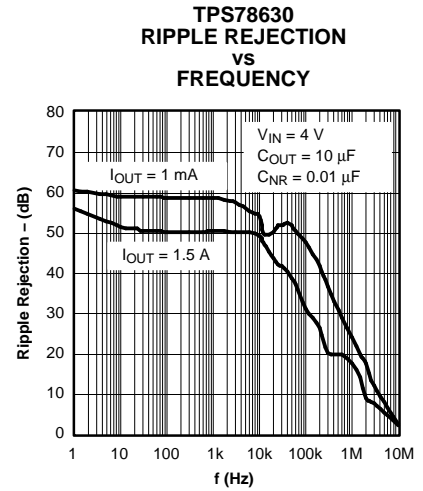


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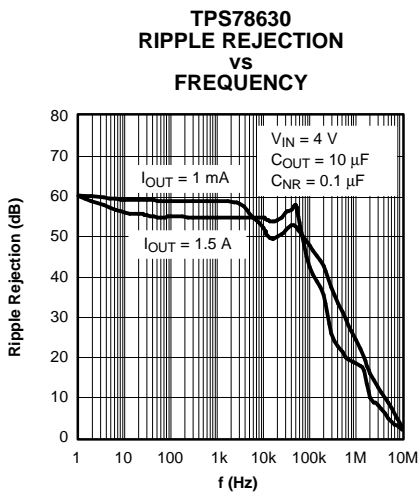


Figure 10.

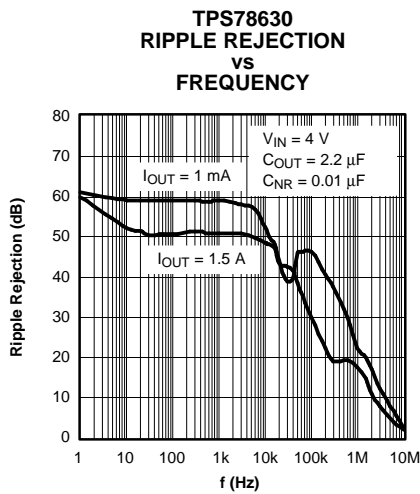


Figure 11.

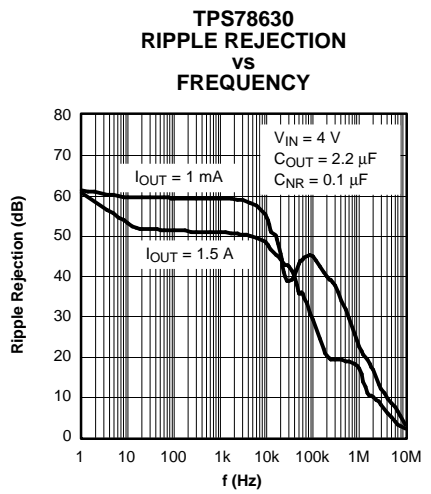


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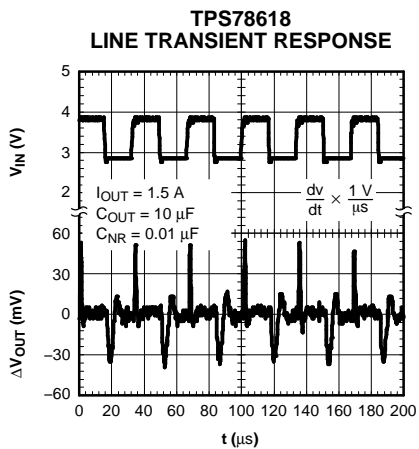


Figure 13.

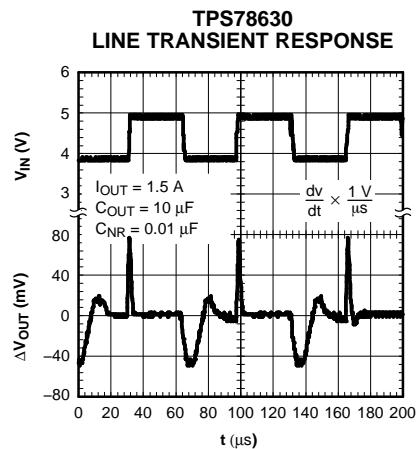


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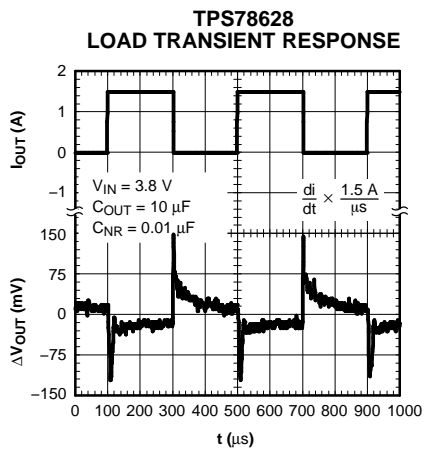


Figure 15.

TYPICAL CHARACTERISTICS (continued)

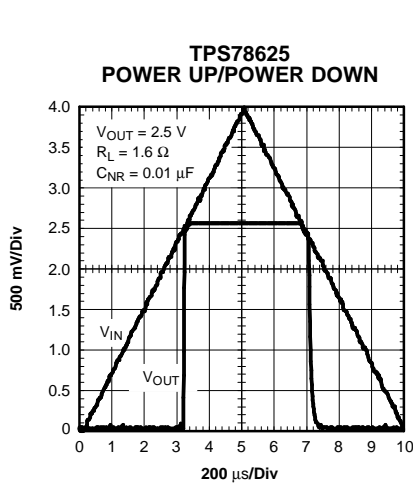


Figure 16.

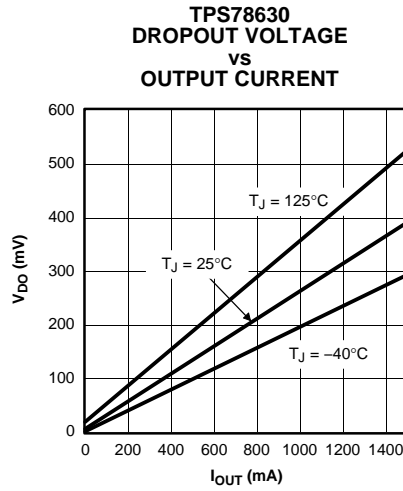


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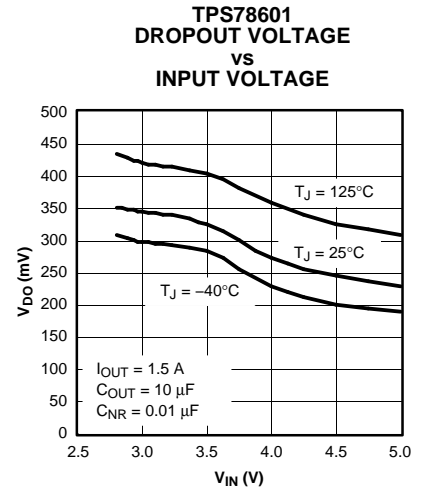


Figure 18.

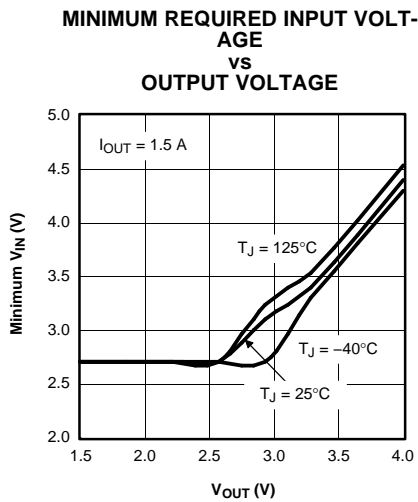


Figure 19.

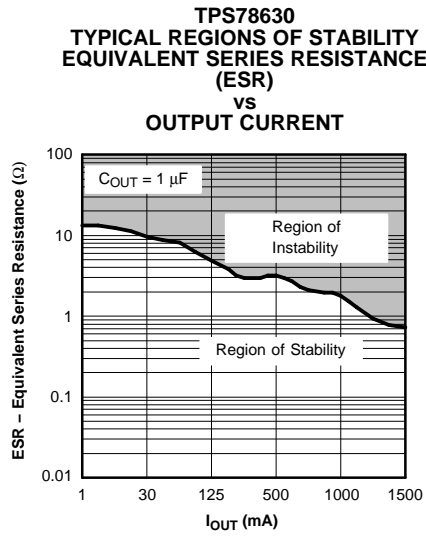


Figure 20.

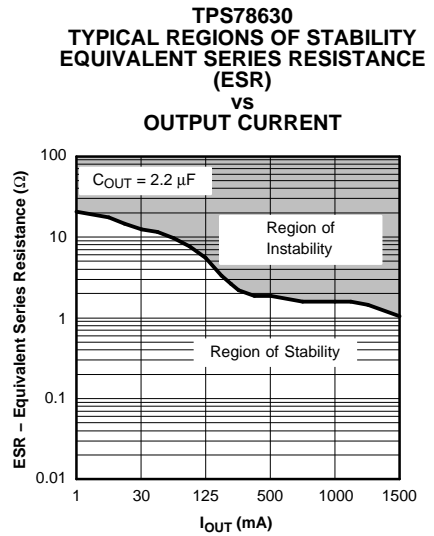


Figure 21.

TYPICAL CHARACTERISTICS (continued)

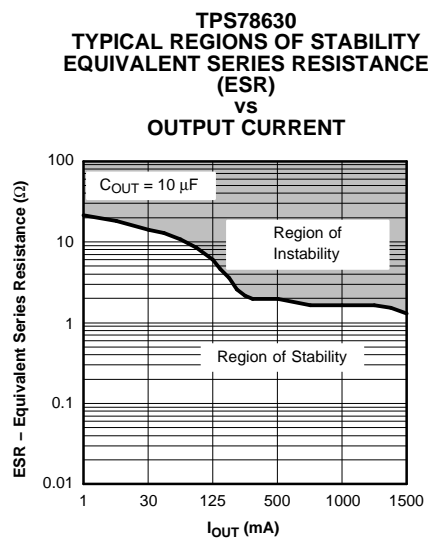


Figure 22.

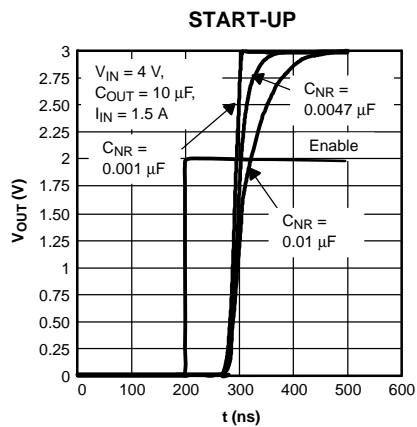


Figure 23.

APPLICATION INFORMATION

The TPS786xx family of low-dropout (LDO) regulators has been optimized for use in noise-sensitive equipment. The device features extremely low dropout voltages, high PSRR, ultralow output noise, low quiescent current (265 μA typically), and enable input to reduce supply currents to less than 1 μA when the regulator is turned off.

A typical application circuit is shown in Figure 24.

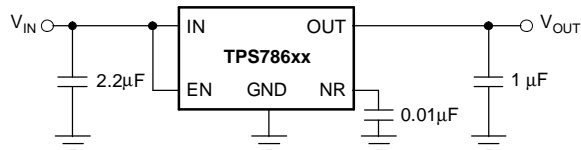


Figure 24. Typical Application Circuit

External Capacitor Requirements

A 2.2- μF or larger ceramic input bypass capacitor, connected between IN and GND and located close to the TPS786xx, is required for stability and improves transient response, noise rejection, and ripple rejection. A higher-value input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

Like most low dropout regulators, the TPS786xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance is 1 μF . Any 1 μF or larger ceramic capacitor is suitable.

The internal voltage reference is a key source of noise in an LDO regulator. The TPS786xx has an NR pin which is connected to the voltage reference through a 250-k Ω internal resistor. The 250-k Ω internal resistor, in conjunction with an external bypass capacitor connected to the NR pin, creates a low pass filter to reduce the voltage reference noise and, therefore, the noise at the regulator output. In order for the regulator to operate properly, the current

flow out of the NR pin must be at a minimum, because any leakage current creates an IR drop across the internal resistor, thus creating an output error. Therefore, the bypass capacitor must have minimal leakage current. The bypass capacitor should be no more than 0.1- μF to ensure that it is fully charged during the quickstart time provided by the internal switch shown in the functional block diagram.

For example, the TPS78630 exhibits only 48 μV_{RMS} of output voltage noise using a 0.1- μF ceramic bypass capacitor and a 10- μF ceramic output capacitor. Note that the output starts up slower as the bypass capacitance increases due to the RC time constant at the bypass pin that is created by the internal 250-k Ω resistor and external capacitor.

Board Layout Recommendation to Improve PSRR and Noise Performance

To improve ac measurements like PSRR, output noise, and transient response, it is recommended that the board be designed with separate ground planes for V_{IN} and V_{OUT} , with each ground plane connected only at the ground pin of the device. In addition, the ground connection for the bypass capacitor should connect directly to the ground pin of the device.

Regulator Mounting

The tab of the SOT223-6 package is electrically connected to ground. For best thermal performance, the tab of the surface-mount version should be soldered directly to a circuit-board copper area. Increasing the copper area improves heat dissipation.

Solder pad footprint recommendations for the devices are presented in an application bulletin *Solder Pad Recommendations for Surface-Mount Devices*, literature number AB-132, available from the TI web site (www.ti.com).

Programming the TPS78601 Adjustable LDO Regulator

The output voltage of the TPS78601 adjustable regulator is programmed using an external resistor divider as shown in Figure 25. The output voltage is calculated using Equation 1:

$$V_O / V_{\text{ref}} \times \left(1 - \frac{R1}{R2}\right) \quad (1)$$

where:

- $V_{\text{REF}} = 1.2246 \text{ V}$ typ (the internal reference voltage)

Resistors R1 and R2 should be chosen for approximately 40- μA divider current. Lower value resistors can be used for improved noise performance, but the device wastes more power. Higher values should be avoided, as leakage current at FB increases the output voltage error. The recommended design procedure is to choose $R2 = 30.1 \text{ k}\Omega$ to set the divider current at 40 μA , $C1 = 15 \text{ pF}$ for stability, and then calculate R1 using Equation 2:

$$R1 / \left(\frac{V_O}{V_{\text{ref}}} - 1\right) \times R2 \quad (2)$$

In order to improve the stability of the adjustable version, it is suggested that a small compensation capacitor be placed between OUT and FB. The approximate value of this capacitor can be calculated using Equation 3:

$$C1 = \frac{(3 \times 10^{-7}) \times (R1 \times R2)}{(R1 + R2)} \quad (3)$$

The suggested value of this capacitor for several resistor ratios is shown in the table below. If this capacitor is not used (such as in a unity-gain configuration), then the minimum recommended output capacitor is 2.2 μF instead of 1 μF .

Regulator Protection

The TPS786xx PMOS-pass transistor has a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting might be appropriate.

The TPS786xx features internal current limiting and thermal protection. During normal operation, the TPS786xx limits output current to approximately 2.8 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds approximately 165°C, thermal-protection circuitry shuts it down. Once the device has cooled down to below approximately 140°C, regulator operation resumes.

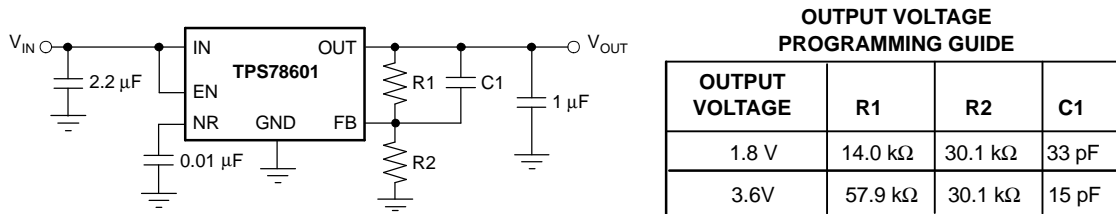


Figure 25. TPS78601 Adjustable LDO Regulator Programming

THERMAL INFORMATION

The amount of heat that an LDO linear regulator generates is directly proportional to the amount of power it dissipates during operation. All integrated circuits have a maximum allowable junction temperature (T_{JMAX}) above which normal operation is not assured. A system designer must design the operating environment so that the operating junction temperature (T_J) does not exceed the maximum junction temperature (T_{JMAX}). The two main environmental variables that a designer can use to improve thermal performance are air flow and external heatsinks. The purpose of this information is to aid the designer in determining the proper operating environment for a linear regulator that is operating at a specific power level.

In general, the maximum expected power ($P_{D(max)}$) consumed by a linear regulator is computed as shown in Equation 4:

$$P_{D(max)} = (V_{I(av)} / V_{O(av)} - 1) \times I_{O(av)} \times V_{I(av)} - V_{I(av)} \times I_{(Q)} \quad (4)$$

where:

- $V_{I(av)}$ is the average input voltage.
- $V_{O(av)}$ is the average output voltage.
- $I_{O(av)}$ is the average output current.
- $I_{(Q)}$ is the quiescent current.

For most TI LDO regulators, the quiescent current is insignificant compared to the average output current; therefore, the term $V_{I(av)} \times I_{(Q)}$ can be neglected. The operating junction temperature is computed by adding the ambient temperature (T_A) and the increase in

temperature due to the regulator's power dissipation. The temperature rise is computed by multiplying the maximum expected power dissipation by the sum of the thermal resistances between the junction and the case ($R_{\theta JC}$), the case to heatsink ($R_{\theta CS}$), and the heatsink to ambient ($R_{\theta SA}$). Thermal resistances are measures of how effectively an object dissipates heat. Typically, the larger the device, the more surface area available for power dissipation and the lower the object's thermal resistance.

Figure 26 illustrates these thermal resistances for (a) a SOT223 package mounted in a JEDEC low-K board, and (b) a DDPAK package mounted on a JEDEC high-K board.

Equation 5 summarizes the computation:

$$T_J = T_A + P_{D(max)} \times (R_{\theta JC} + R_{\theta CS} + R_{\theta SA}) \quad (5)$$

The $R_{\theta JC}$ is specific to each regulator as determined by its package, lead frame, and die size provided in the regulator's data sheet. The $R_{\theta SA}$ is a function of the type and size of heatsink. For example, *black body radiator* type heatsinks can have $R_{\theta CS}$ values ranging from 5°C/W for very large heatsinks to 50°C/W for very small heatsinks. The $R_{\theta CS}$ is a function of how the package is attached to the heatsink. For example, if a thermal compound is used to attach a heatsink to a SOT223 package, $R_{\theta CS}$ of 1°C/W is reasonable.

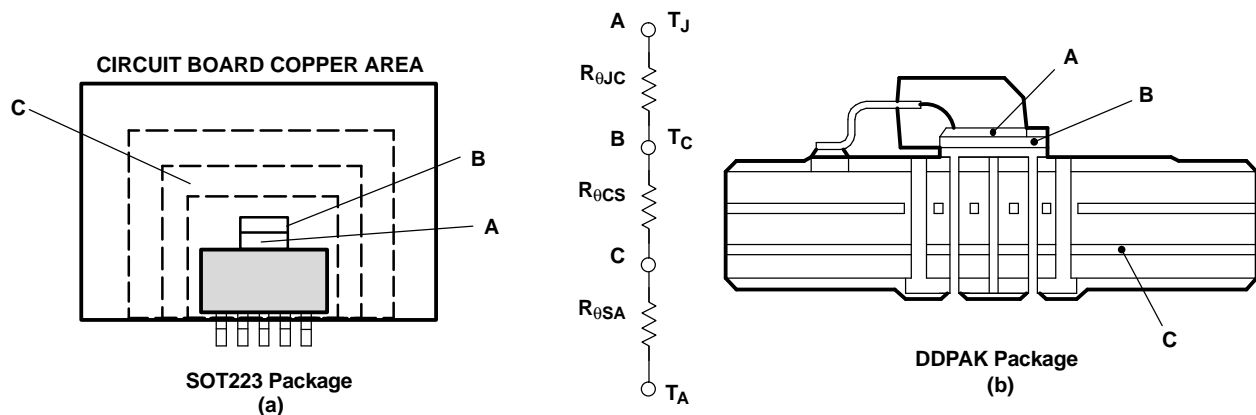


Figure 26. Thermal Resistances

Even if no external *black body radiator* type heatsink is attached to the package, the board on which the regulator is mounted provides some heatsinking through the pin solder connections. Some packages, like the DDPAK and SOT223 packages, use a copper plane underneath the package or the circuit board's ground plane for additional heatsinking to improve their thermal performance. Computer-aided thermal modeling can be used to compute very accurate approximations of an integrated circuit's thermal performance in different operating environments (e.g., different types of circuit boards, different types and sizes of heatsinks, and different air flows, etc.). Using these models, the three thermal resistances can be combined into one thermal resistance between junction and ambient ($R_{\theta JA}$). This $R_{\theta JA}$ is valid only for the specific operating environment used in the computer model.

Equation 5 simplifies into Equation 6:

$$T_J - T_A \times P_{D,max} \times R_{\theta JA} \quad (6)$$

Rearranging Equation 6 gives Equation 7:

$$R_{\theta JA} \times \frac{T_J - T_A}{P_{D,max}} \quad (7)$$

Using Equation 6 and the computer model generated curves shown in Figure 27 and Figure 30, a designer can quickly compute the required heatsink thermal resistance/board area for a given ambient temperature, power dissipation, and operating environment.

DDPAK Power Dissipation

The DDPAK package provides an effective means of managing power dissipation in surface mount applications. The DDPAK package dimensions are provided in the *Mechanical Data* section at the end of the data sheet. The addition of a copper plane directly underneath the DDPAK package enhances the thermal performance of the package.

To illustrate, the TPS78625 in a DDPAK package was chosen. For this example, the average input voltage is 5 V, the output voltage is 2.5 V, the average output current is 1 A, the ambient temperature 55°C, the air flow is 150 LFM, and the operating environment is the same as documented below. Neglecting the quiescent current, the maximum average power is shown in Equation 8:

$$P_{D,max} - (5 \times 2.5) V \times 1 A - 2.5 W \quad (8)$$

Substituting $T_{J,max}$ for T_J into Equation 6 gives Equation 9:

$$R_{\theta JA,max} - (125 \times 55)^\circ C / 2.5 W - 28^\circ C/W \quad (9)$$

From Figure 27, *DDPAK Thermal Resistance vs Copper Heatsink Area*, the ground plane needs to be 1 cm² for the part to dissipate 2.5 W. The operating environment used in the computer model to construct Figure 27 consisted of a standard JEDEC High-K board (2S2P) with a 1 oz. internal copper plane and ground plane. The package is soldered to a 2 oz. copper pad. The pad is tied through thermal vias to the 1 oz. ground plane. Figure 28 shows the side view of the operating environment used in the computer model.

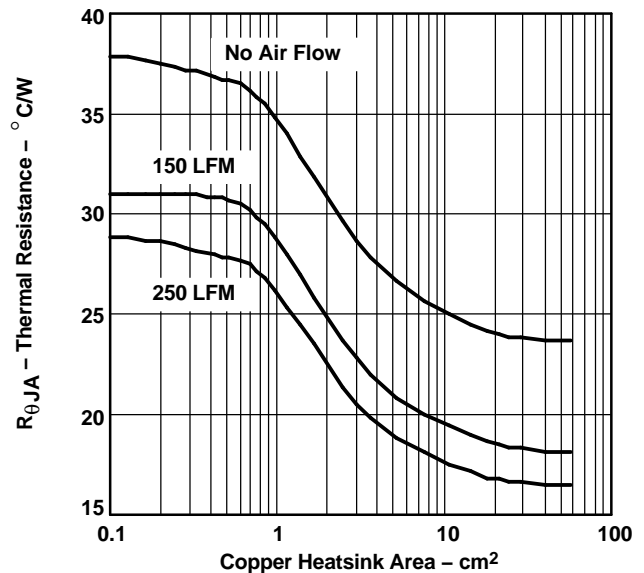


Figure 27. DDPAK Thermal Resistance vs Copper Heatsink Area

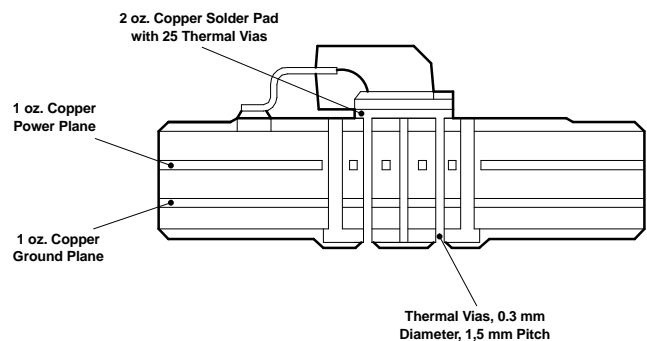


Figure 28. DDPAK Thermal Resistance

From the data in Figure 29 and rearranging Equation 6, the maximum power dissipation for a different ground plane area and a specific ambient temperature can be computed.

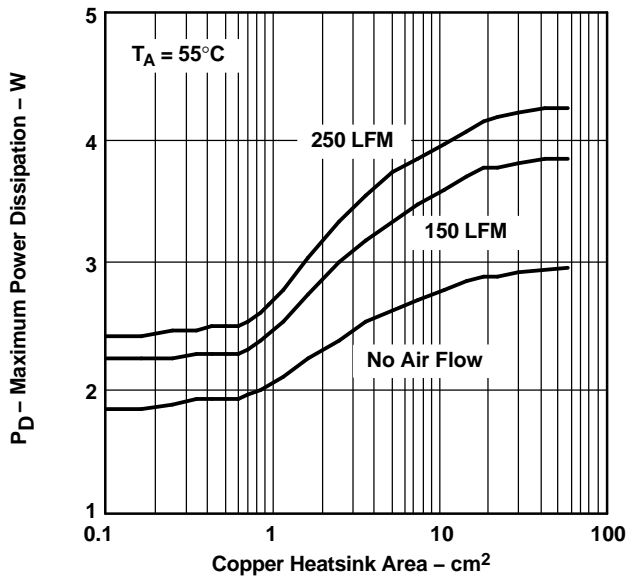


Figure 29. Maximum Power Dissipation vs Copper Heatsink Area

SOT223 Power Dissipation

The SOT223 package provides an effective means of managing power dissipation in surface mount applications. The SOT223 package dimensions are provided in the *Mechanical Data* section at the end of the data sheet. The addition of a copper plane directly underneath the SOT223 package enhances the thermal performance of the package.

To illustrate, the TPS78625 in a SOT223 package was chosen. For this example, the average input voltage is 3.3 V, the output voltage is 2.5 V, the average output current is 1 A, the ambient temperature 55°C, no air flow is present, and the operating environment is the same as documented below. Neglecting the quiescent current, the maximum average power is calculated as shown in Equation 10:

$$P_{Dmax} = (3.3 \times 2.5) \text{ V} \times 1 \text{ A} = 800 \text{ mW} \quad (10)$$

Substituting T_{Jmax} for T_J into Equation 6 gives Equation 11:

$$R_{\theta JA} \text{ max} = (125 \times 55)^\circ\text{C} / 800 \text{ mW} = 87.5^\circ\text{C/W} \quad (11)$$

From Figure 30, $R_{\theta JA}$ vs PCB Copper Area, the ground plane needs to be 0.55 in² for the part to

dissipate 800 mW. The operating environment used to construct Figure 30 consisted of a board with 1 oz. copper planes. The package is soldered to a 1 oz. copper pad on the top of the board. The pad is tied through thermal vias to the 1 oz. ground plane.

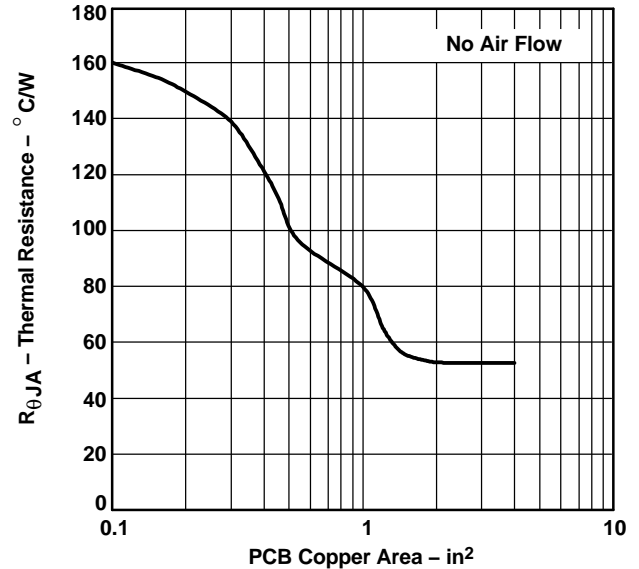


Figure 30. SOT223 Thermal Resistance vs PCB Area

From the data in Figure 30 and rearranging Equation 6, the maximum power dissipation for a different ground plane area and a specific ambient temperature can be computed (see Figure 31).

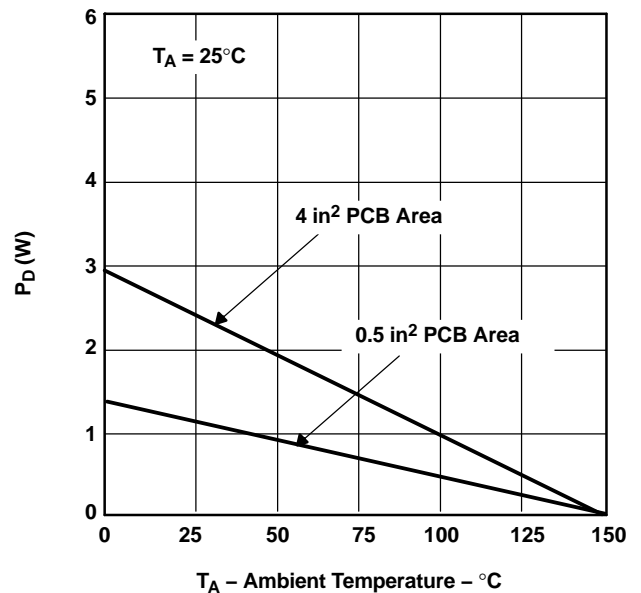


Figure 31. SOT223 Power Dissipation

PACKAGING INFORMATION

ORDERABLE DEVICE	STATUS(1)	PACKAGE TYPE	PACKAGE DRAWING	PINS	PACKAGE QTY
TPS78601DCQ	ACTIVE	SOP	DCQ	6	49
TPS78601DCQR	ACTIVE	SOP	DCQ	6	2500
TPS78601KTT	OBSOLETE	PFM	KTT	5	
TPS78601KTTR	ACTIVE	PFM	KTT	5	500
TPS78601KTTT	ACTIVE	PFM	KTT	5	50
TPS78618DCQ	ACTIVE	SOP	DCQ	6	78
TPS78618DCQR	ACTIVE	SOP	DCQ	6	2500
TPS78618KTT	OBSOLETE	PFM	KTT	5	
TPS78618KTTR	ACTIVE	PFM	KTT	5	500
TPS78618KTTT	ACTIVE	PFM	KTT	5	50
TPS78625DCQ	ACTIVE	SOP	DCQ	6	78
TPS78625DCQR	ACTIVE	SOP	DCQ	6	2500
TPS78625KTT	OBSOLETE	PFM	KTT	5	
TPS78625KTTR	ACTIVE	PFM	KTT	5	500
TPS78625KTTT	ACTIVE	PFM	KTT	5	50
TPS78628DCQ	ACTIVE	SOP	DCQ	6	78
TPS78628DCQR	ACTIVE	SOP	DCQ	6	2500
TPS78628KTT	OBSOLETE	PFM	KTT	5	
TPS78628KTTR	ACTIVE	PFM	KTT	5	500
TPS78628KTTT	ACTIVE	PFM	KTT	5	50
TPS78630DCQ	ACTIVE	SOP	DCQ	6	78
TPS78630DCQR	ACTIVE	SOP	DCQ	6	2500
TPS78630KTT	OBSOLETE	PFM	KTT	5	
TPS78630KTTR	ACTIVE	PFM	KTT	5	500
TPS78630KTTT	ACTIVE	PFM	KTT	5	50
TPS78633DCQ	ACTIVE	SOP	DCQ	6	78
TPS78633DCQR	ACTIVE	SOP	DCQ	6	2500
TPS78633KTT	OBSOLETE	PFM	KTT	5	
TPS78633KTTR	ACTIVE	PFM	KTT	5	500
TPS78633KTTT	ACTIVE	PFM	KTT	5	50

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

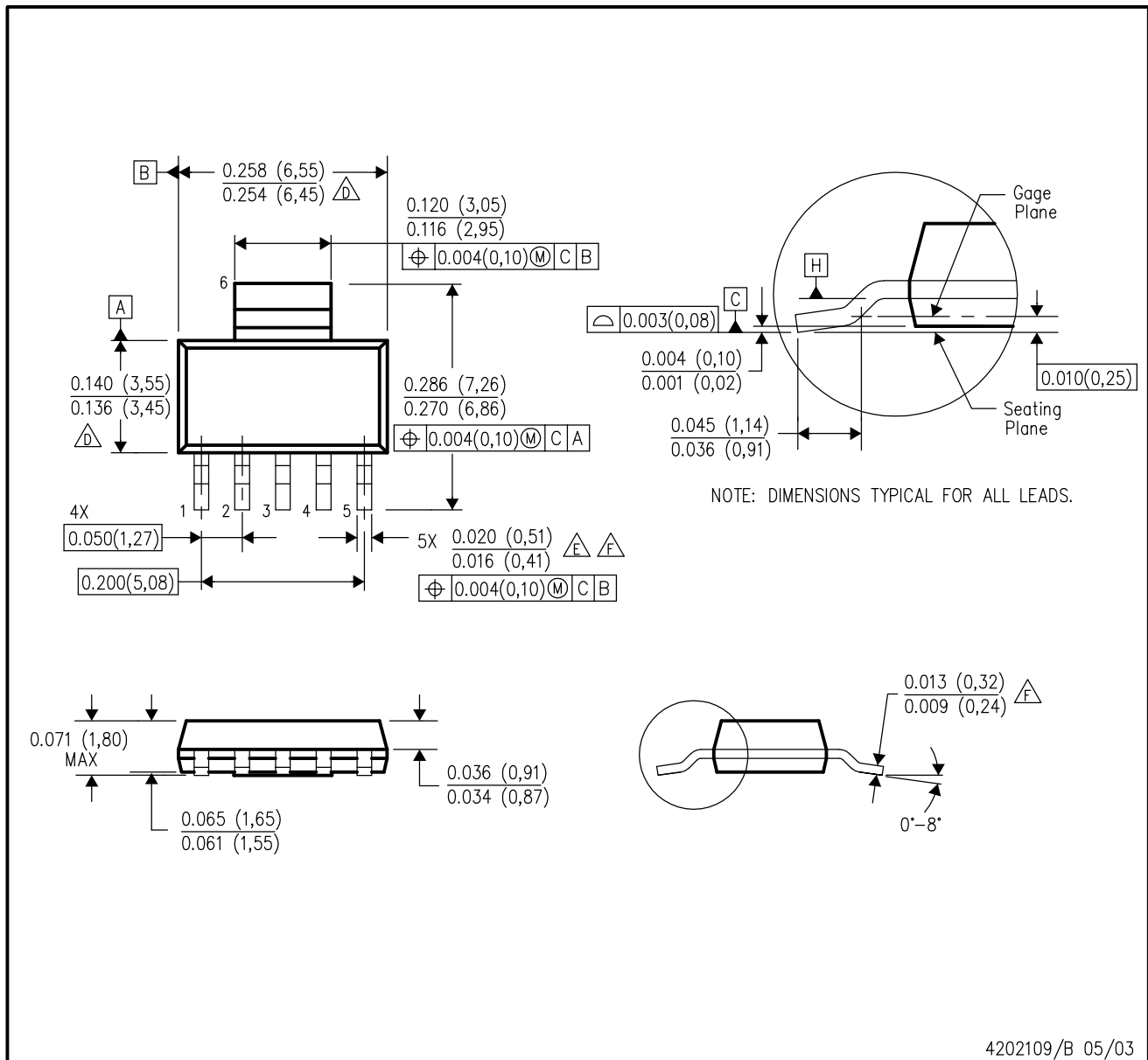
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

DCQ (R-PDSO-G6)

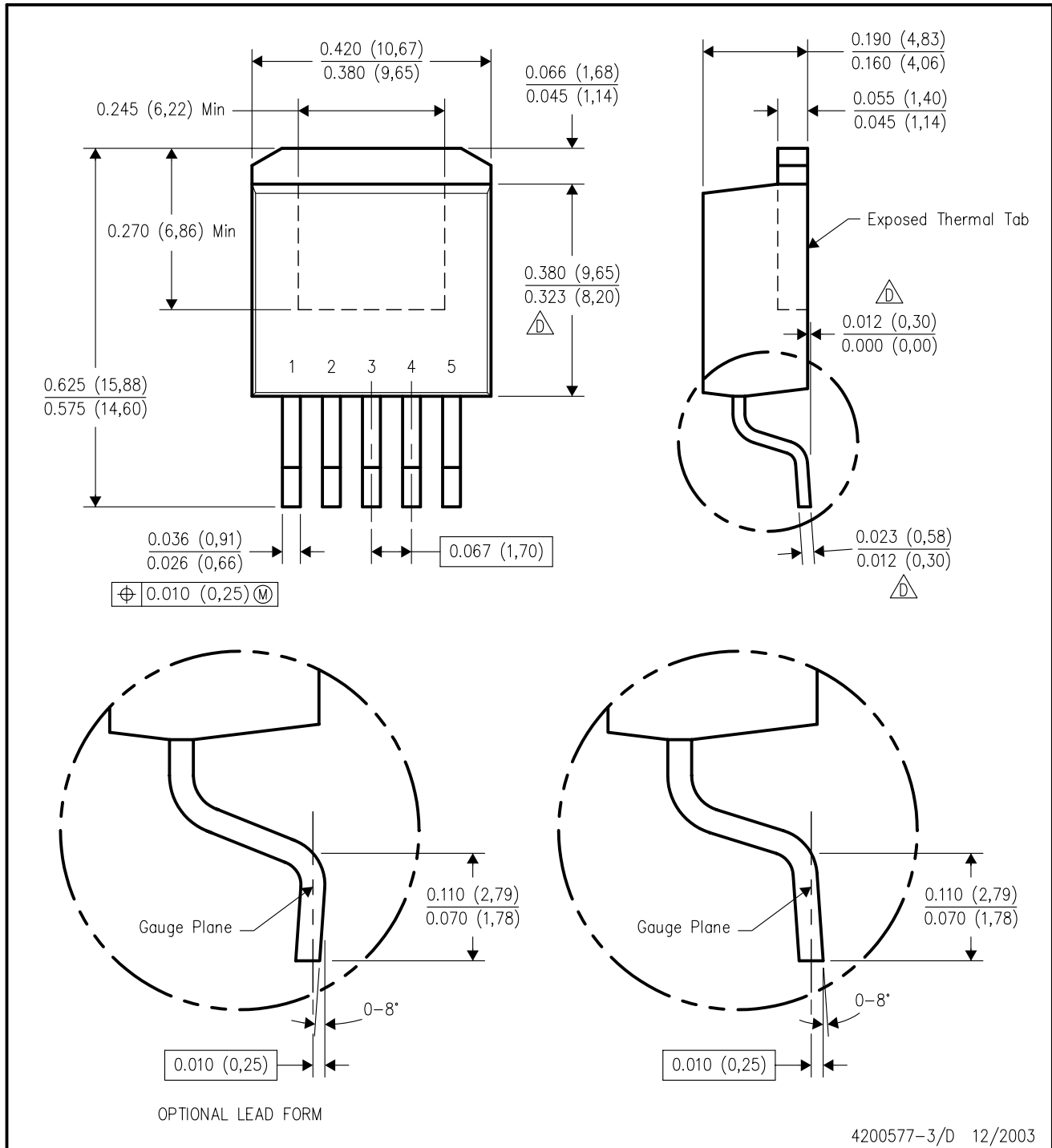
PLASTIC SMALL-OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Controlling dimension in inches.
 - $\triangle D$ Body length and width dimensions are determined at the outermost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs, and interlead flash, but including any mismatch between the top and the bottom of the plastic body.
 - $\triangle E$ Lead width dimension does not include dambar protrusion.
 - $\triangle F$ Lead width and thickness dimensions apply to solder plated leads.
 - G. Interlead flash allow 0.008 inch max.
 - H. Gate burr/protrusion max. 0.006 inch.
 - I. Datums A and B are to be determined at Datum H.
 - J. Package dimensions per JEDEC outline drawing TO-261, issue B, dated Feb. 1999. This variation is not yet included.

KTT (R-PSFM-G5)

PLASTIC FLANGE-MOUNT PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Dimensions do not include mold protrusions, not to exceed 0.006 (0,15).
- ⚠ Falls within JEDEC TO-263 variation BA, except minimum lead thickness, maximum seating height, and minimum body length.

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